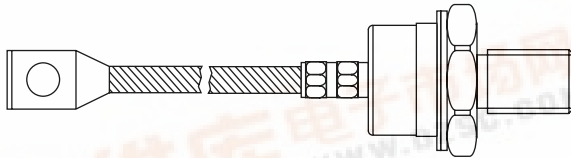




240U(R).. Series

Vishay High Power Products

Standard Recovery Diodes (Stud Version), 320 A



DO-205AB (DO-9)

FEATURES

- Diffused diode
- Wide current range
- High voltage ratings up to 1200 V
- High surge current capabilities
- Stud cathode and stud anode version
- Hermetic metal case
- RoHS compliant
- Designed and qualified for industrial level



RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	320 A
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TYPICAL APPLICATIONS

- Welders
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications
- Battery charges
- Freewheeling diodes

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		320	A
	T_C	100	°C
$I_{F(RMS)}$		500	A
I_{FSM}	50 Hz	4500	A
	60 Hz	4700	
I^2t	50 Hz	101	kA ² s
	60 Hz	92	
V_{RRM}	Range	600 to 1200	V
T_J		- 40 to 180	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
240U(R)..	60	600	700	15
	80	800	900	
	100	1000	1100	
	120	1200	1300	



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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			320	A
					100	°C
Maximum RMS forward current	I _{F(RMS)}	DC at 80 °C case temperature			500	A
Maximum peak, one cycle forward, non-repetitive surge current	I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = T _J maximum	4500	
		t = 8.3 ms			4700	
		t = 10 ms	100 % V _{RRM} reapplied		3800	
		t = 8.3 ms			4000	
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		101	kA ² s
		t = 8.3 ms			92	
		t = 10 ms	100 % V _{RRM} reapplied		72	
		t = 8.3 ms			66	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied			1010	kA ² √s
Slope resistance	r _f	T _J = T _J maximum			0.6	mΩ
Threshold voltage	V _{F(T0)}				0.83	V
Maximum forward voltage drop	V _{FM}	I _{pk} = 750 A, T _J = 25 °C, t _p = 10 ms sinusoidal wave			1.33	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T_J, T_{Stg}		- 40 to 180	°C
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.18	K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased	0.8	
Maximum allowed mounting torque + 0 - 20 %		Not lubricated threads	37 (330)	N · m (lbf · in)
		Lubricated threads	28 (250)	
Approximate weight			250	g
Case style		See dimensions - link at the end of datasheet	DO-205AB (DO-9)	

ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.019	0.015	$T_J = T_J$ maximum	K/W
120°	0.023	0.025		
90°	0.030	0.034		
60°	0.045	0.047		
30°	0.076	0.076		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



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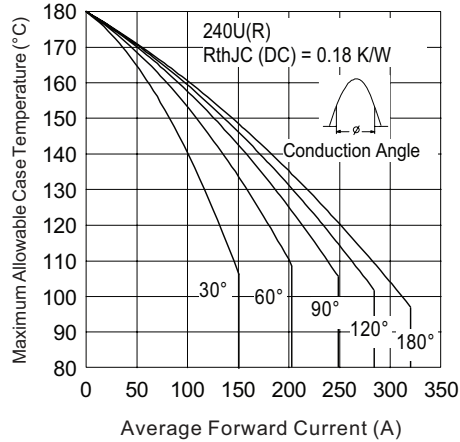


Fig. 1 - Current Ratings Characteristics

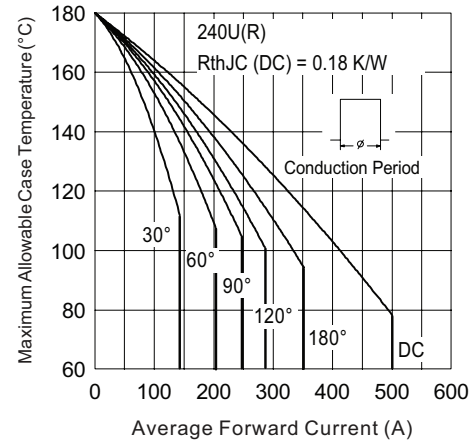


Fig. 2 - Current Ratings Characteristics

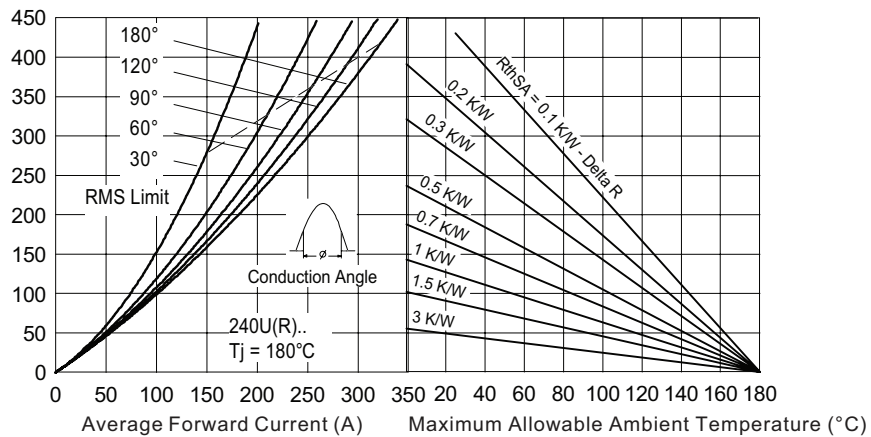


Fig. 3 - Forward Power Loss Characteristics

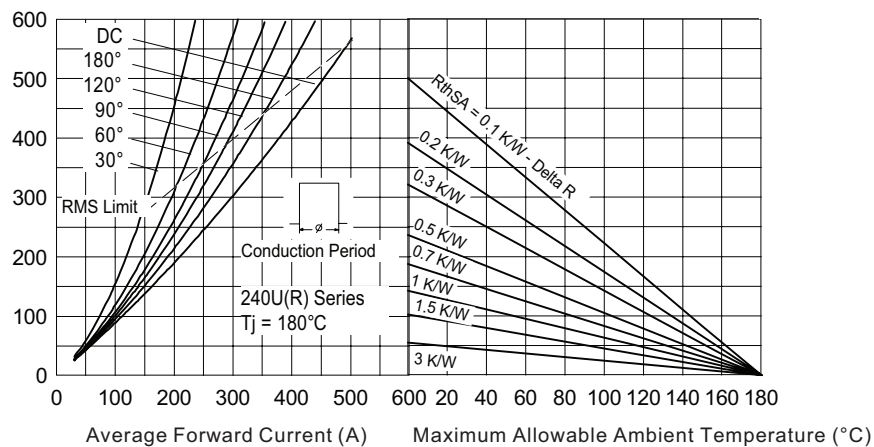


Fig. 4 - Forward Power Loss Characteristics

240U(R).. Series

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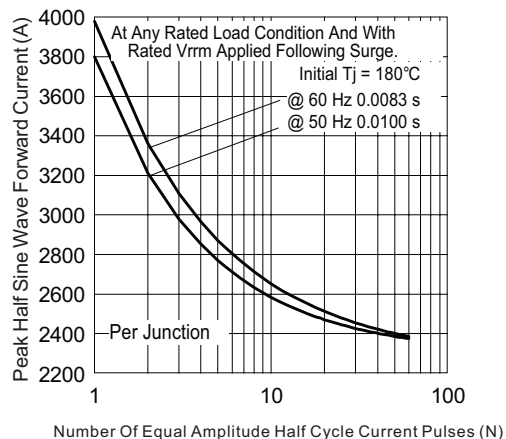


Fig. 5 - Maximum Non-Repetitive Surge Current

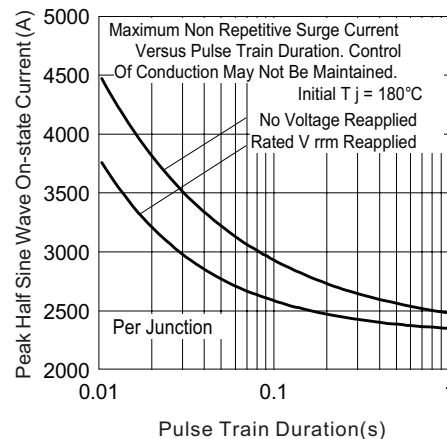


Fig. 6 - Maximum Non-Repetitive Surge Current

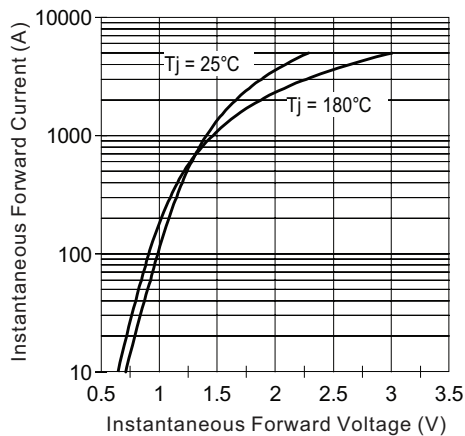


Fig. 7 - Forward Voltage Drop Characteristics

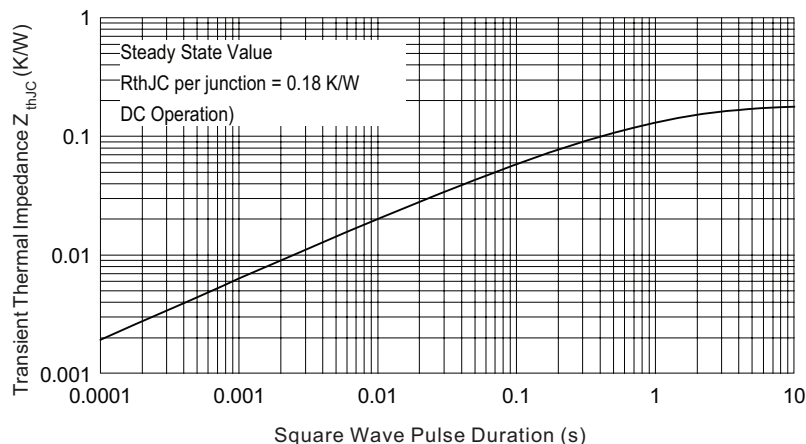
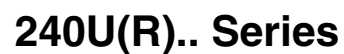


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic



ORDERING INFORMATION TABLE

1	-	24 = Essential part number
2	-	0 = Standard device
3	-	U = Stud normal polarity (cathode to stud)
4	-	• None = Stud normal polarity (cathode to stud) • R = Stud reverse polarity (anode to stud)
5	-	Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
6	-	Diffused diode

LINKS TO RELATED DOCUMENTS

www.vishay.com



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